



Features:

- Isolated mounting base 4000V~
- Pressure contact technology with increased power cycling capability
- Space and weight saving

Typical Applications:

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

V _{RRM} , V _{DRM}	Type & Outline	
	Type	Outline
2600V	MTx135-26-216F3	MTx135-26-216F3B
2800V	MTx135-28-216F3	MTx135-28-216F3B
3000V	MTx135-30-216F3	MTx135-30-216F3B
3200V	MTx135-32-216F3	MTx135-32-216F3B
3400V	MTx135-34-216F3	MTx135-34-216F3B
3600V	MTx135-36-216F3	MTx135-36-216F3B
3600V		MT135-36-216F3BG

MTx stands for any type of **MTC, MTA, MTK**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz Single side cooled, T _c =85°C	125			135	A
I _{T(RMS)}	RMS on-state current					212	A
I _{DRM} I _{RDM}	Repetitive peak current	at V _{DRM} at V _{RRM}	125			25	mA
I _{TSM}	Surge on-state current	V _R =60%V _{RRM} , t=10ms half sine	125			2.6	kA
I ² t	I ² t for fusing coordination		125			34	10 ³ A ² s
V _{TO}	Threshold voltage		125			0.88	V
r _T	On-state slope resistance					2.40	mΩ
V _{TM}	Peak on-state voltage	I _{TM} =410A	25			2.58	V
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =67%V _{DRM}	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	Gate source 1.5A t _r ≤ 0.5μs Repetitive	125			200	A/μs
I _{GT}	Gate trigger current	V _A =12V, I _A =1A	25	30		150	mA
V _{GT}	Gate trigger voltage			0.8		2.5	V
I _H	Holding current			10		200	mA
I _L	Latching current					1000	mA
V _{GD}	Non-trigger gate voltage	V _{DM} =67%V _{DRM}	125			0.20	V
R _{th(j-c)}	Thermal resistance Junction to case	Single side cooled per chip				0.18	°C/W
R _{th(c-h)}	Thermal resistance case to heatsink	Single side cooled per chip				0.08	°C/W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} : 1mA(MAX)		4000			V
F _m	Terminal connection torque(M6)			4.5		6	N·m
	Mounting torque(M6)			4.5		6	N·m
T _{vj}	Junction temperature			-40		125	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				320		g
Outline	216F3, 216F3B						

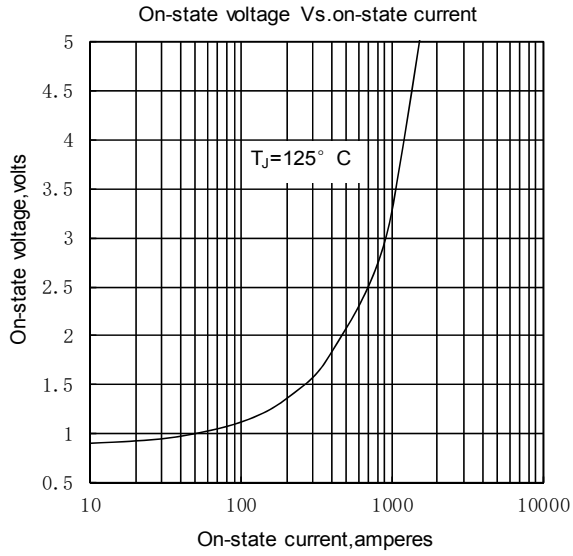


Fig.1

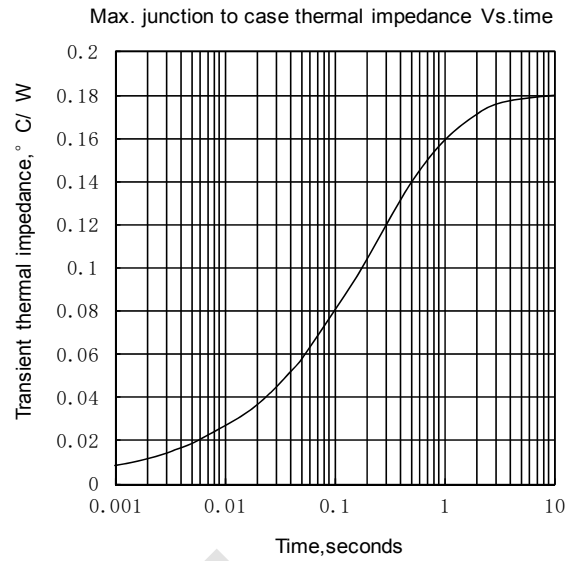


Fig.2

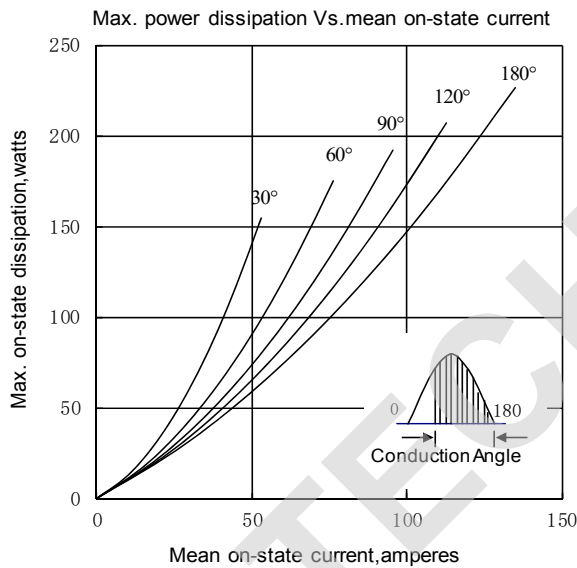


Fig.3

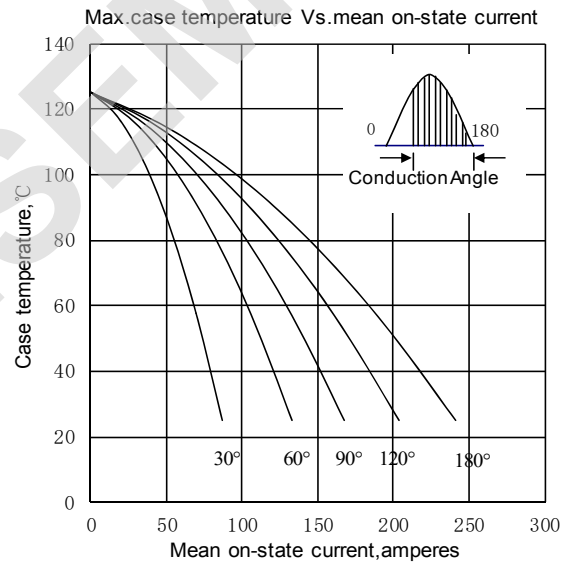


Fig.4

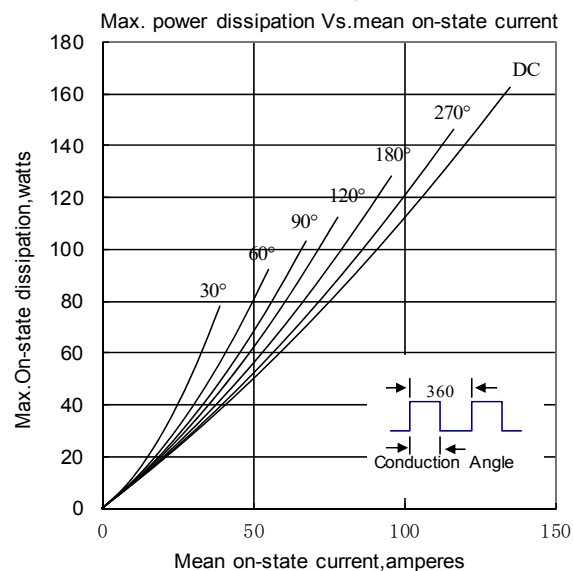


Fig.5

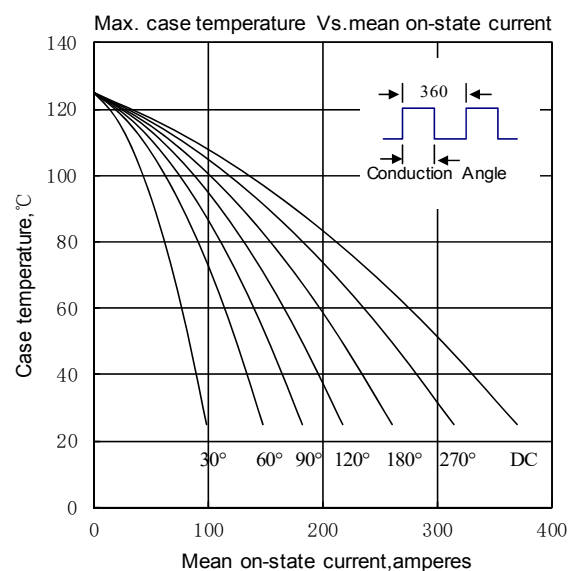


Fig.6

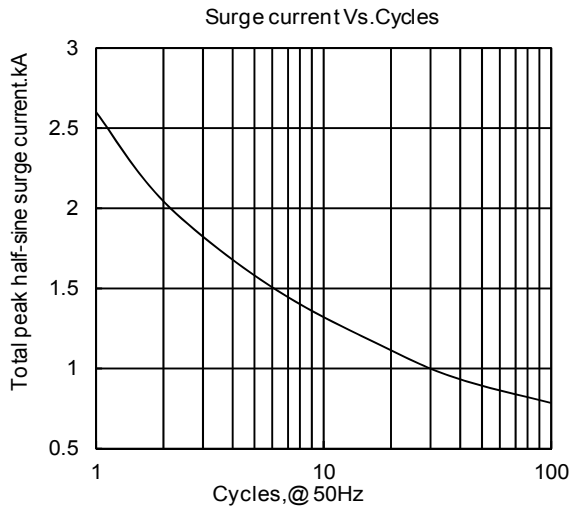


Fig. 7

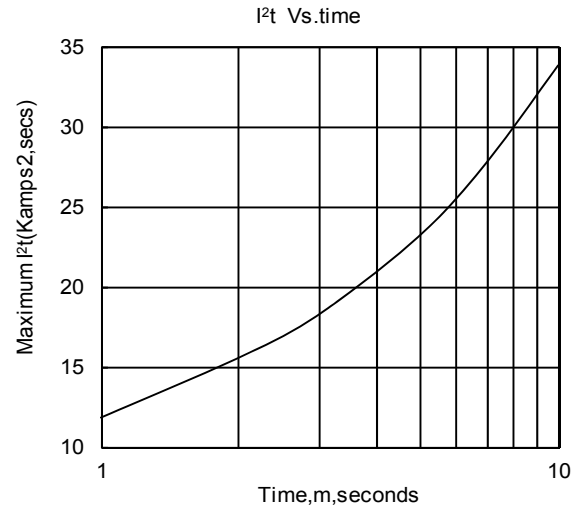


Fig. 8

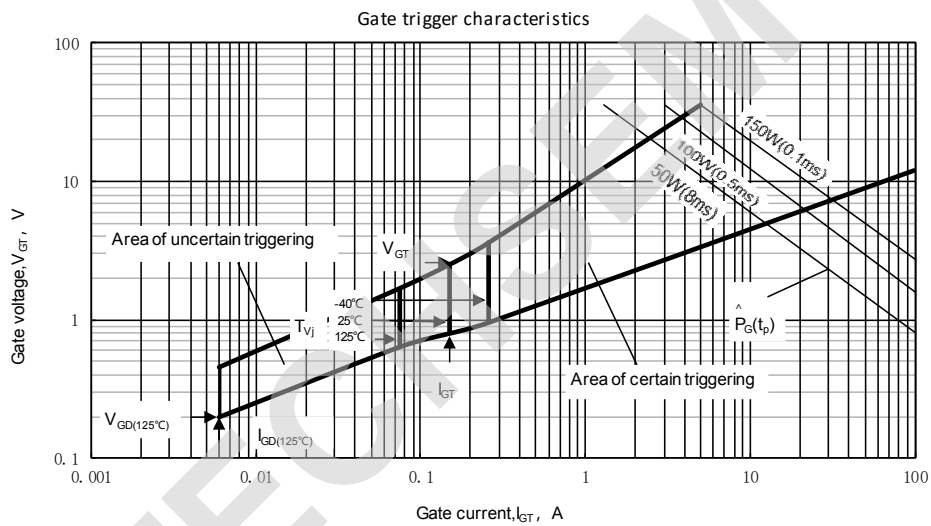
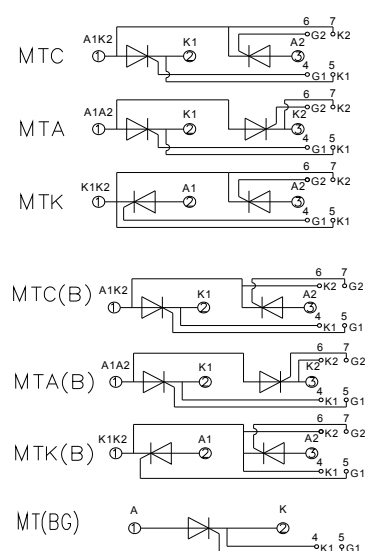
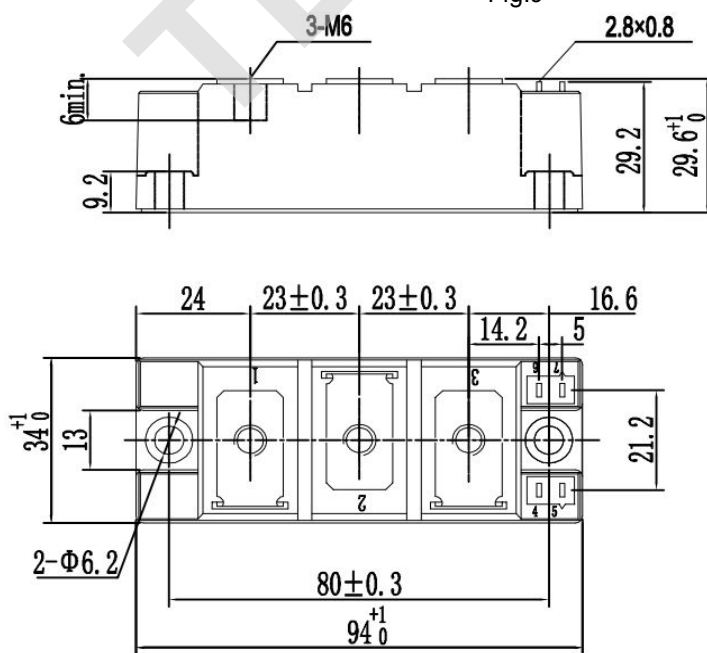


Fig.9

Outline:



Unmarked dimensional tolerance: ±0.5mm

TECHSEM reserves the right to change specifications without notice.